





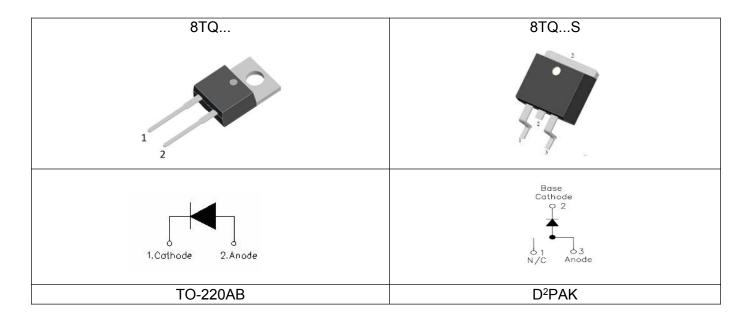
8TQ080/S/ 8TQ100/S SCHOTTKY RECTIFIER

Features

- 150[°]C T_J operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- · Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection



Maximum Ratings:

| Characteristics | Symbol | Condition | | Max. | Units |
|--|---------------------|--|-----|----------|-------|
| Peak Repetitive Reverse Voltage | V _{RRM} | - | 80 | (8TQ080) | |
| Working Peak Reverse Voltage DC Blocking Voltage | V_{RWM} | | 100 | (8TQ100) | V |
| Average Rectified Forward Current | I _{F (AV)} | 50% duty cycle @Tc=116°C, rectangular wave form | | 8 | Α |
| Peak One Cycle Non-Repetitive Surge Current | I _{FSM} | 8.3ms, Half Sine pulse | | 330 | Α |
| Non-Repetitive Avalanche Energy | E _{AS} | T _J =25℃,I _{AS} =0.50A,L=60mH | | 7.5 | mJ |
| Repetitive Avalanche Current | lar | Current decaying linearly to zero in 1 µsec Frequency limited by T _J max.V _A =1.5×V _R typical | | 0.50 | A |

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Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|------------------------|-----------------|--|--------|--------|-------|
| Forward Voltage Drop* | V _{F1} | @ 8A, Pulse, T _J = 25 °C | 0.71 | 0.75 | V |
| | V _{F2} | @ 8A, Pulse, T _J = 125 °C | 0.56 | 0.58 | V |
| Reverse Current * | I _{R1} | $@V_R = \text{rated } V_R$ $T_J = 25 \ ^{\circ}C$ | 0.0003 | 1.0 | mA |
| | I _{R2} | $@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}C$ | 0.02 | 7 | mA |
| Junction Capacitance | Ст | $@V_R = 5V, T_C = 25 \degree C$ $f_{SIG} = 1MHz$ | 400 | 500 | pF |
| Series Inductance | Ls | Measured lead to lead 5 mm from package body | 8.0 | - | nH |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/µs |

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

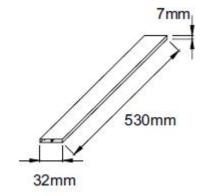
| Characteristics | Symbol | Condition | Specification | Units |
|---|----------------------------|---|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Junction to Case | $R_{	heta JC}$ | DC operation | 2.0 | °C/W |
| Typical Thermal Resistance Case to Heat Sink | R _{θCS} | Mounting surface, smooth and greased(only for TO-220) | 0.50 | °C/W |
| Case Style | TO-220ACD ² PAK | | | |

Tube Specification

| Device | Package | Weight | Shipping |
|--------|----------|--------|---------------|
| 8TQ | TO-220AC | 1.8g | 50pcs / tube |
| 8TQS | D² PAK | 1.85g | 800pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AC)



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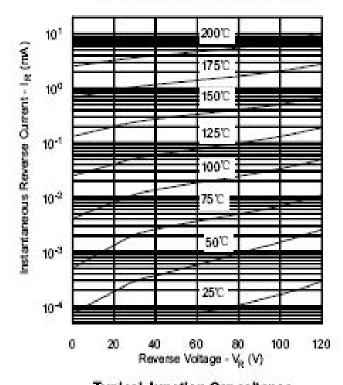


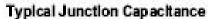
Ratings and Characteristics Curves

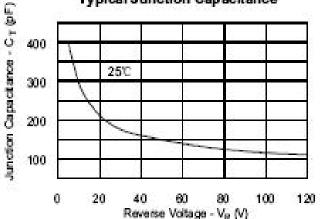
Typical Forward Characteristics

10¹ 175°C Instantaneous Forward Current - 1_p (A) 10^{0} 12510 25% 10-1 10^{-2} 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 Forward Voltage Drop - V_F (V)

Typical Reverse Characteristics







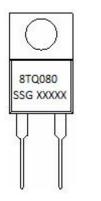
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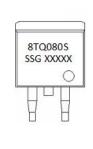






Marking Diagram





Where XXXXX is YYWWL

= Forward Current (8A) TQ

= Device Type = Reverse Voltage (80/100V) 80/100

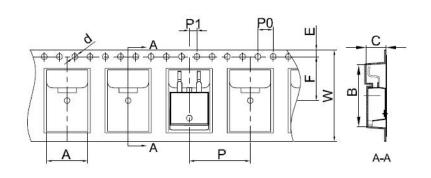
= Package type SSG = SSG

= Year ΥY $\mathsf{W}\mathsf{W}$ = Week = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



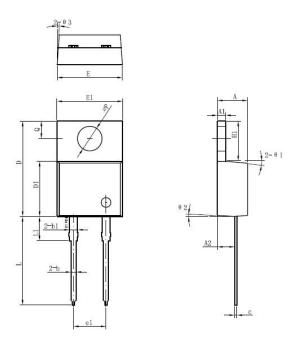
| Symbol | Millimeters | | | |
|---------|-------------|-------|--|--|
| Зуппоот | Min. | Max. | | |
| Α | 10.70 | 10.90 | | |
| В | 16.03 | 16.23 | | |
| С | 5.11 | 5.31 | | |
| d | 1.45 | 1.65 | | |
| E | 1.65 | 1.85 | | |
| F | 11.40 | 11.60 | | |
| P0 | 3.90 | 4.10 | | |
| Р | 15.90 | 16.10 | | |
| P1 | 1.90 | 2.10 | | |
| W | 23.90 | 24.30 | | |





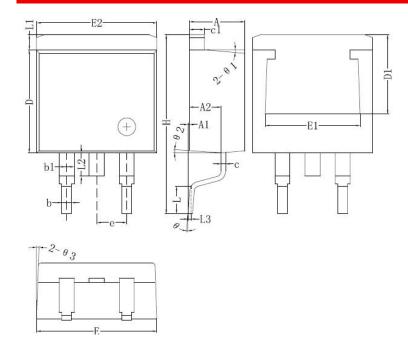


Mechanical Dimensions TO-220AC



| Symbol | Dimensions in millimeters | | | |
|--------|---------------------------|-------|-------|--|
| | Min. Typical | | Max. | |
| Α | 4.47 | 4.70 | 4.85 | |
| A1 | 1.17 | 1.27 | 1.37 | |
| A2 | 2.52 | 2.69 | 2.89 | |
| b | 0.71 | 0.81 | 0.96 | |
| b1 | 1.17 | 1.27 | 1.37 | |
| С | 0.31 | 0.38 | 0.61 | |
| D | 14.64 | 14.94 | 15.24 | |
| D1 | 8.50 | 8.07 | 8.90 | |
| E | 10.01 | 10.16 | 10.31 | |
| E1 | 9.98 | 10.18 | 10.38 | |
| e1 | 4.98 | 5.08 | 5.18 | |
| H1 | 6.04 | 6.24 | 6.44 | |
| L | 13.00 | 13.86 | 14.08 | |
| L1 | 3.56 | 3.80 | 3.96 | |
| ФР | 3.74 | 3.84 | 4.04 | |
| Q | 2.54 | 2.74 | 2.94 | |
| Θ1 | | 5° | | |
| Θ2 | | 4° | | |
| Θ3 | | 4° | | |

Mechanical Dimensions D²PAK



| Symbol | Millimeters | | | | |
|--------|-------------|---------|-------|--|--|
| | Min. | Typical | Max. | | |
| Α | 4.47 | 4.70 | 4.85 | | |
| A1 | 0 | 0.10 | 0.25 | | |
| A2 | 2.59 | 2.69 | 2.89 | | |
| b | 0.71 | 0.81 | 0.96 | | |
| b1 | 1.17 | 1.27 | 1.37 | | |
| С | 0.31 | 0.38 | 0.61 | | |
| c1 | 1.17 | 1.27 | 1.37 | | |
| D | 8.50 | 8.70 | 8.90 | | |
| D1 | 6.40 | | | | |
| E | 10.01 | 10.16 | 10.31 | | |
| E1 | 7.6 | | | | |
| E2 | 9.98 | 10.08 | 10.31 | | |
| е | | 2.54 | | | |
| Н | 14.6 | 15.1 | 15.6 | | |
| L | 2.00 | 2.30 | 2.74 | | |
| L1 | 1.12 | 1.27 | 1.42 | | |
| L2 | 1.30 | | 2.20 | | |
| L3 | | 0.25BSC | | | |
| е | 0 | - | 8° | | |
| e1 | | 5° | | | |
| e2 | | 4° | | | |
| e3 | | 4° | | | |

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